☐ MN101C61D, MN101C61G

Туре	MN101C61D (under development)	MN101C61G				
ROM (×8-bit)	64 K	128 K				
RAM (×8-bit)	3 K	12 K				
Package	TQFP080-P-1212D *Lead-free					
Minimum Instruction Execution Time	Standard: 0.1 μs (at 2.5 V to 3.6 V, 20 MHz) 0.2 μs (at 2.1 V to 3.6 V, 10 MHz) 0.5 μs (at 1.8 V to 3.6 V, 4 MHz)* 125 μs (at 1.8 V to 3.6 V, 32 kHz)*					
	Double speed: 0.1 µs (at 2.5 V t 0.2 µs (at 2.1 V t 0.5 µs (at 1.8 V t	o 3.6 V, 10 MHz) o 3.6 V, 5 MHz) o 3.6 V, 2 MHz)* to 3.6 V, 32 kHz)*				
Interrupts	• RESET • Watchdog • External 0 • External 1 • External 2 • External 3 • External 4 • External 5 • Timer 0 • Timer 1 • Timer 2 • Timer 3 • Timer 4 • Timer 5 • Timer 6 • Time base • Serial 0 reception • Serial 0 transmission • Serial 1 reception • Serial 1 transmission • Serial 2 • Serial 3 • Automatic transfer finish • A/D conversion finish • Timer 7 (2 systems) • Key interrupts (8 lines)					
Timer Counter	Timer counter 0: 8-bit × 1 (square-wave/8-bit PWM output, event count, generation of remote control carrier, pulse width measurement) Clock source					
	Timer counter 1:8-bit × 1 (square-wave output, event count, synchronous output event) Clock source					
	Timer counter 0, 1 can be cascade-connected.					
	-	frequency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation XI oscillation clock frequency; external clock input				
	Timer counter 3: 8-bit × 1 (square-wave output, event count, generation of remote control carrier) Clock source					
	Timer counter 2, 3 can be cascade-connected.					
	clock frequency; 1/1 of 1/1 of external clock in	k frequency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillati XI oscillation clock frequency; put frequency				
	Interrupt source	easurement, serial 0 baud rate timer) frequency; 1/1, 1/4, 1/16, 1/32, 1/64 of OSC oscillation clock flation clock frequency; tfrequency				

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Timer Counter (Continue)		Timer counter 6: 8-bit freerun timer Clock source				
						Time base timer (one-minute count setting) Clock source
		DMA controller (automatic data transfer) Max. Transfer cycles ······· 255 Starting factor ······ external request, various types of interrupt, software Transfer mode ······ 1-byte transfer, word transfer, burst transfer				
		Serial Interface		Serial 0 : synchronous type / UART (full-duplex) × 1 Clock source		
				Serial 1: synchronous type / UART (full-duplex) × 1 Clock source		
I/O Pins	I/O	62 • Common use • Specified pull-up resistor available • Input/output selectable (bit unit)				
	Input	6 • Common use • Specified pull-up resistor available				
A/D Inputs	nputs 10-Bit × 6-ch. (with S/H)					
Special Ports		Buzzer output, remote control carrier signal output, high-current drive port				

See the next page for electrical characteristics, pin assignment and support tool.

Electrical Characteristics

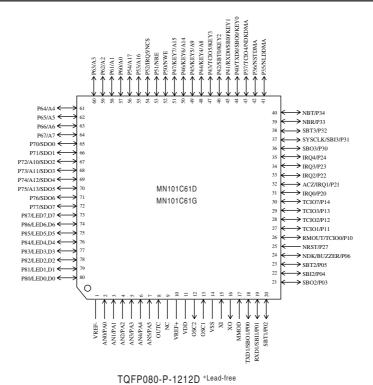
Supply current

Parameter	Symbol	Condition		Limit		
raiailletei	Syllibol			typ	max	Unit
	IDD1	fosc = 20 MHz, VDD = 3 V, (fs = fosc/2)		5	12	mA
Operating supply current	IDD2	fosc = 8.39 MHz, VDD = 3 V, (fs = fosc/2)		2	5	mA
	IDD3	fx = 32.768 kHz, VDD = 3 V, (fs = fx/2)			40	μА
Cupply ourrent at HALT	IDD4	fx = 32.768 kHz, VDD = 3 V, Ta = 25°C		4	8	μА
Supply current at HALT	IDD5	fx = 32.768 kHz, VDD = 3 V			30	μА
Supply current at STOP	IDD6	VDD = 3 V, Ta = 25°C			2	μА
Supply current at STOP	IDD7	VDD = 3 V			20	μА

 $Ta = -40^{\circ}C \text{ to } +85^{\circ}C, VDD = 1.8 \text{ V to } 3.6 \text{ V}, VSS = 0 \text{ V}$

Note) Ta = -20° C to $+70^{\circ}$ C for a flash memory built-in version. Supply voltage range ans supply current ratings are also different from the values mentioned above. Refer to Chapter 18 "Flash EEPROM" for detailes

Pin Assignment



NC serves as the VPP pin in the MN101CF61G, and cannot be used as a user pin.

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Support Tool

In-circuit Emulator	PX-ICE101C / D + PX-PRB101C61-TQFP080-P-1212-M		
Flash Memory Built-in Type	Туре	MN101CF61G	
	ROM (× 8-bit)	128 K	
	RAM (× 8-bit)	12 K	
	Minimum instruction execution time	0.1 μs (at 2.7 V to 3.6 V, 20 MHz)	
		0.2 µs (at 2.7 V to 3.6 V, 10 MHz)	
		0.5 µs (at 2.7 V to 3.6 V, 4 MHz)	
		125 µs (at 2.7 V to 3.6 V, 32 kHz)	
	Package	TQFP080-P-1212D *Lead-free	
	Туре	MN101CF60G	
	ROM (× 8-bit)	128 K	
	RAM (× 8-bit)	12 K	
	Minimum instruction execution time	0.1 μs (at 2.5 V to 3.0 V, 20 MHz)	
		0.2 µs (at 2.2 V to 3.0 V, 10 MHz)	
		$0.5~\mu s$ (at $2.2~V$ to $3.0~V, 4~MHz)$	
		125 µs (at 2.2 V to 3.0 V, 32 kHz)	
	Package	TQFP080-P-1212D *Lead-free	

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